<b>Services Microsemi</b>
SCOTTSDALE DIVISION

DESCRIPTION

This "fast recovery" rectifier diode series is military qualified to MIL-PRF-19500/429 and is ideal for high-reliability applications where a failure cannot be tolerated. These industry-recognized 1.0 Amp rated rectifiers for working peak reverse voltages from 200 to 1000 volts are hermetically sealed with voidless-glass construction using an internal "Category I" metallurgical bond. These devices are also available in surface mount MELF package configurations by adding a "US" suffix (see separate data sheet for 1N5615US thru 1N5623US). Microsemi also offers numerous other rectifier products to meet higher and lower current ratings with various recovery time speed requirements including fast and ultrafast device

# 1N5615 thru 1N5623

# VOIDLESS-HERMETICALLY SEALED FAST RECOVERY GLASS RECTIFIEINS

# APPEARANCE "A" Package

## ELECTRICAL CHARACTERISTICS

ELECTRICAL CHARACTERISTICS										
	WORKING	MINIMUM	AVEF	RAGE	FORWAR	REVE	ERSE	CAPACITANCE	MAXIMUM	REVERSE
	PEAK	BREAKDOWN	RECTIFIED		D	CURI	RENT	(MAX.)	SURGE	RECOVERY
TYPE	REVERSE	VOLTAGE	CURRENT		VOLTAGE	(M <i>A</i>	4X.)	C @ V <sub>R</sub> =12 V	CURRENT	(MAX.)
	VOLTAGE	V <sub>BR</sub> @ 50μA	l <sub>o</sub> @	<b>₽ T</b> A	(MAX.) I <sub>R</sub> @ V <sub>RWM</sub>		f=1 MHz	IFSM	(NOTE 3)	
	VRWM	•	(NOTE 1)		V <sub>F</sub> @ 3A				(NOTE 2)	t <sub>rr</sub>
	VOLTS	VOLTS	AMPS		VOLTS	μA		pF	AMPS	ns
			50°C	100°C		25°C	100°C			
1N5615	200	220	1.00	.750	.8 MIN.	.5	25	45	25	150
1N5617	400	440	1.00	.750		.5	25	35	25	150
1N5619	600	660	1.00	.750		.5	25	25	25	250
1N5621	800	880	1.00	.750	1.6	.5	25	20	25	300
1N5623	1000	1100	1.00	.750	MAX.	.5	25	15	25	500

**NOTE 1:** From 1 Amp at  $T_A = 55^{\circ}$ C, derate linearly at 5.56 mA/ °C to 0.75 Amp at  $T_A = 100^{\circ}$ C. From  $T_A = 100^{\circ}$ C, derate linearly at 7.5 mA/°C to 0 Amps at  $T_A = 200^{\circ}$ C. These ambient ratings are for PC boards where thermal resistance from mounting point to ambient is sufficiently controlled where  $T_{J(max)}$  does not exceed 175 °C. **NOTE 2:**  $T_A = 100^{\circ}$ C, f = 60 Hz,  $I_O = 750$  mA for ten 8.3 ms surges @ 1 minute intervals **NOTE 3:**  $I_F = 0.5$  A,  $I_{RM} = 1$  A,  $I_{R(REC)} = 0.250$  A

# Microsemi Scottsdale Division

1N5615 - 1N5623

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# 1N5615 thru 1N5623

# VOIDLESS-HERMETICALLY SEALED FAST RECOVERY GLASS RECTIFIERS

SYMBOLS & DEFINITIONS										
Symbol	Definition									
V <sub>BR</sub>	Minimum Breakdown Voltage: The minimum voltage the device will exhibit at a specified current									
V <sub>RWM</sub>	Working Peak Reverse Voltage: The maximum peak voltage that can be applied over the operating temperature range									
Ι <sub>Ο</sub>	Average Rectified Output Current: Output Current averaged over a full cycle with a 50 hZ or 60 Hz sine-wave input and a 180 degree conduction angle									
V <sub>F</sub>	Maximum Forward Voltage: The maximum forward voltage the device will exhibit at a specified current									
I <sub>R</sub>	Maximum Leakage Current: The maximum leakage current that will flow at the specified voltage and temperature									
С	Capacitance: The capacitance in pF at a frequency of 1 MHz and specified voltage									
t <sub>rr</sub>	Reverse Recovery Time: The time interval between the instant the current passes through zero when changing from the forward direction to the reverse direction and a specified decay point after a peak reverse current occurs.									





# GRAPHS

IR -- CURRENT ("A)



1N5615 - 1N5623



# 1N5615 thru 1N5623

# VOIDLESS-HERMETICALLY SEALED FAST RECOVERY GLASS RECTIFIERS





TYPICAL FORWARD VOLTAGE vs FORWARD CURRENT

# PACKAGE DIMENSIONS



NOTE: Lead tolerance = +0.003/-0.004 inches



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Authorized Distributor

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Microchip:

<u>JANTX1N5623</u> <u>JANTXV1N5621</u> <u>1N5619</u> <u>JANTXV1N5615</u> <u>1N5617</u> <u>JANTX1N5617</u> <u>JAN1N5621</u> <u>JANTX1N5615</u> JANTX1N5619